

- Designed for Complementary Use with BDW94, BDW94A, BDW94B and BDW94C
- 80 W at 25°C Case Temperature
- 12 A Continuous Collector Current
- Minimum h_{FE} of 750 at 3V, 5 A

Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT	
	BDW93		45		
Collector-base voltage (I _E = 0)	BDW93A	W	60	٧	
	BDW93B	V _{CBO}	80		
	BDW93C		100	r	
	BDW93		45	V	
Collector-emitter voltage (I _B = 0)	BDW93A	W	60		
	BDW93B	V _{CEO}	80		
	BDW93C		100		
Emitter-base voltage			5	V	
Continuous collector current			12	Α	
Continuous base current			0.3	Α	
Continuous device dissipation at (or below) 25°C case temperature (see Note 1)		P_{tot}	80	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note 2)		P _{tot}	2	W	
Operating junction temperature range			-65 to +150	°C	
Storage temperature range			-65 to +150	°C	
Operating free-air temperature range			-65 to +150	°C	

NOTES: 1. Derate linearly to 150°C case temperature at the rate of 0.64 W/°C.

^{2.} Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.



electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER TEST CONDITIONS		MIN	TYP	MAX	UNIT				
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C = 100 mA	I _B = 0	(see Note 3)	BDW93 BDW93A BDW93B BDW93C	45 60 80 100			V
I _{CEO}	Collector-emitter cut-off current	$V_{CB} = 40 \text{ V}$ $V_{CB} = 60 \text{ V}$ $V_{CB} = 80 \text{ V}$ $V_{CB} = 80 \text{ V}$	$I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$		BDW93 BDW93A BDW93B BDW93C			1 1 1	mA
Ісво	Collector cut-off current	$V_{CB} = 100 \text{ V}$ $V_{CB} = 45 \text{ V}$ $V_{CB} = 60 \text{ V}$ $V_{CB} = 80 \text{ V}$	I _E = 0 I _E = 0	$T_{C} = 150^{\circ}C$ $T_{C} = 150^{\circ}C$ $T_{C} = 150^{\circ}C$ $T_{C} = 150^{\circ}C$	BDW93 BDW93A BDW93B BDW93C BDW93 BDW93A BDW93B BDW93C			0.1 0.1 0.1 0.1 5 5 5	mA
I _{EBO}	Emitter cut-off current	V _{EB} = 5 V	I _C = 0					2	mA
h _{FE}	Forward current transfer ratio	V-	$I_C = 3 A$ $I_C = 10 A$ $I_C = 5 A$	(see Notes 3 and	i 4)	1000 100 750		20000	
V _{CE(sat)}	Collector-emitter saturation voltage		$I_{C} = 5 A$ $I_{C} = 10 A$	(see Notes 3 and 4)				2 3	٧
V _{BE(sat)}	Base-emitter saturation voltage	$I_B = 20 \text{ mA}$ $I_B = 100 \text{ mA}$	$I_C = 5 A$ $I_C = 10 A$	(see Notes 3 and 4)				2.5 4	V
V _{EC}	Parallel diode forward voltage	I _E = 5 A I _E = 10 A	$I_{B} = 0$ $I_{B} = 0$					2 4	V

NOTES: 3. These parameters must be measured using pulse techniques, t_p = 300 μ s, duty cycle \leq 2%.

thermal characteristics

	PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			1.56	°C/W
$R_{\theta,JA}$	Junction to free air thermal resistance			62.5	°C/W

^{4.} These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

TYPICAL CHARACTERISTICS

TYPICAL DC CURRENT GAIN vs **COLLECTOR CURRENT** TCS130AE 50000 -40°C 25°C = 100°C h_{FE} - Typical DC Current Gain 000 000 3 V = 300 μs, duty cycle < 2% 100 0.5 1.0 10 20 I_c - Collector Current - A

Figure 1.

COLLECTOR-EMITTER SATURATION VOLTAGE

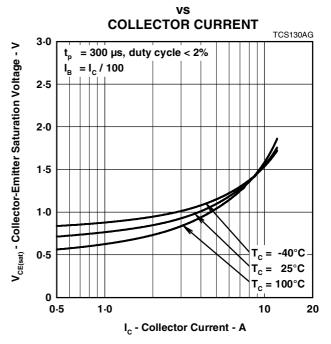
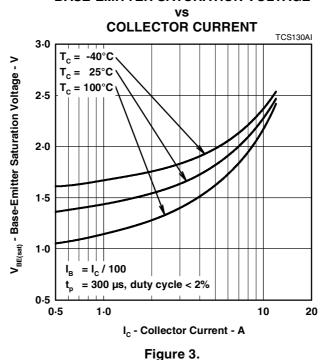


Figure 2.

BASE-EMITTER SATURATION VOLTAGE



PRODUCT INFORMATION

THERMAL INFORMATION

MAXIMUM POWER DISSIPATION

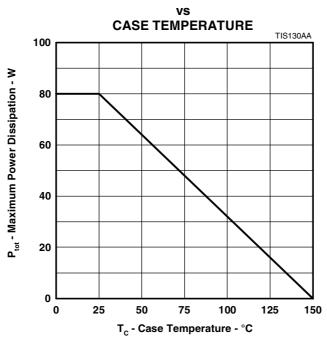


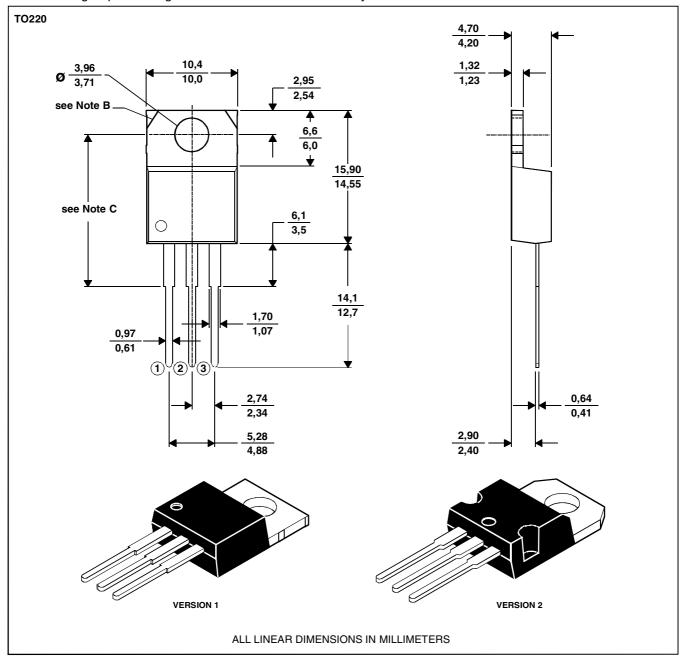
Figure 4.

MECHANICAL DATA

TO-220

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTES: A. The centre pin is in electrical contact with the mounting tab.

- B. Mounting tab corner profile according to package version.
- C. Typical fixing hole centre stand off height according to package version.

Version 1, 18.0 mm. Version 2, 17.6 mm.

MDXXBE